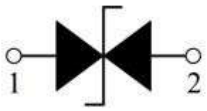
ESD Protector



DFN1006-2L

Features

- 100W peak pulse power per line (t_P = 8/20μs)
- DFN1006 package
- Replacement for MLV(0402)
- Bidirectional configurations
- Response time is typically < 1ns
- Low clamping voltage
- RoHS compliant
- Transient protection for data lines to IEC61000-4-2(ESD) ±15KV(air), ±8KV(contact); IEC61000-4-4 (EFT) 40A (5/50ns)

Marking Code	
ESD9BZ5V0C	C

Mechanical characteristics

- Lead finish:100% matte Sn(Tin)
- Mounting position: Any
- Qualified max reflow temperature:260℃
- Device meets MSL 1 requirements
- Pure tin plating: 7 ~ 17 um
- Pin flatness:≤3mil

Description

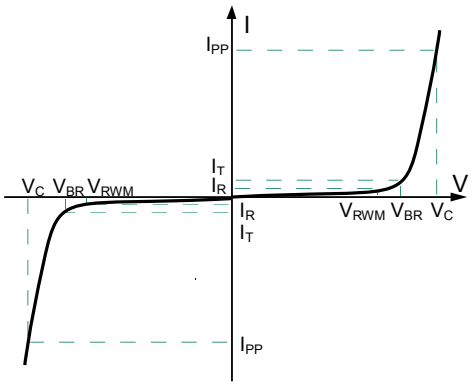
The ESD9BZ5V0C protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, low operating voltage. It gives designer the flexibility to protect one bi-directional line in applications where arrays are not practical.

Application

- Cellular phones
- Portable devices
- Digital cameras
- Power supplies

Electronics Parameter

Symbol	Parameter
V_{RWM}	Peak Reverse Working Voltage
I_R	Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
I_{PP}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
P_{PP}	Peak Pulse Power
C_J	Junction Capacitance
I_F	Forward Current
V_F	Forward Voltage @ I_F



Electrical Characteristics(TA = 25 °C unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Peak Reverse Working Voltage	V_{RWM}				5	V
Breakdown Voltage	V_{BR}	I_t = 1mA	5.6		8.5	V
Reverse Leakage Current	I_R	V_{RWM} = 5V T=25℃			1.0	μA
Maximum Reverse Peak Pulse Current	I_{PP}			5.5		A
Clamping Voltage	V_C	I_{PP}=1A			10	V
Clamping Voltage	V_C	I_{PP}=3A			15	V
Clamping Voltage	V_C	I_{PP}=5A			21	V
Junction Capacitance	C_j	V_R=0V f = 1MHz		0.3		pF

Absolute maximum rating

Rating	Symbol	Value	Units
Peak Pulse Power (t_p=8/20μs)	P_{pp}	100	W
Operating Temperature	T_J	-55 to +150	℃
Storage Temperature	T_{STG}	-55 to +150	℃

Typical Characteristics

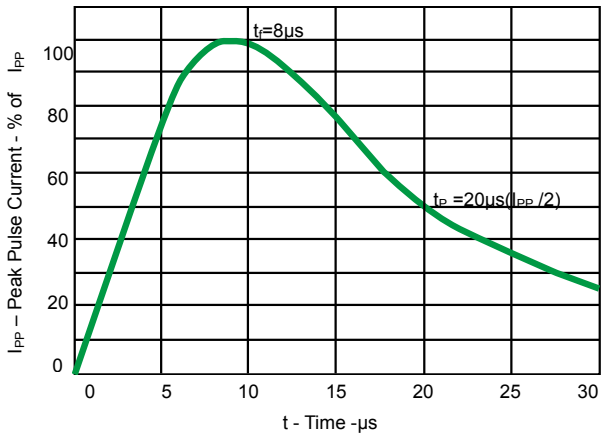


Fig 1.Pulse Waveform

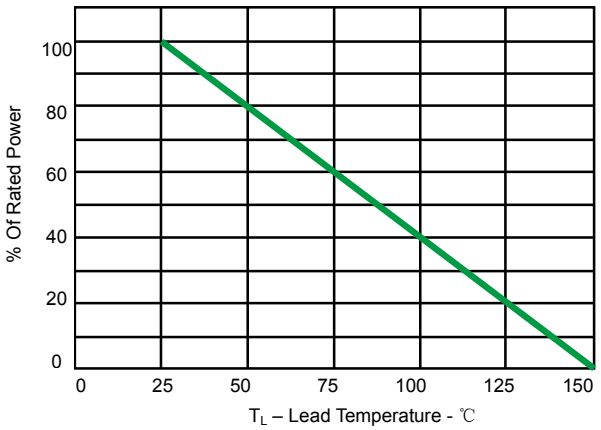


Fig 2.Power Derating Curve

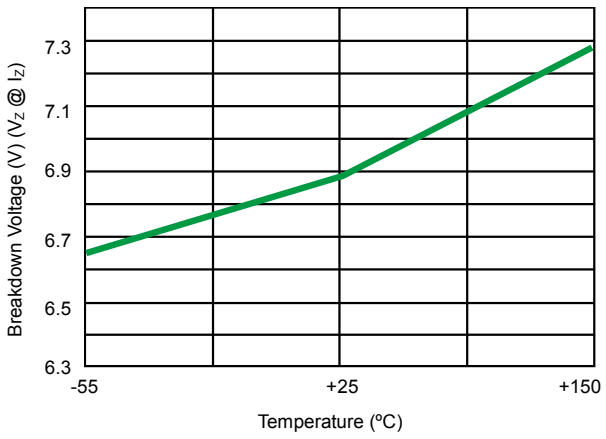


Fig 3.Typical Breakdown Voltage vs. Temperature

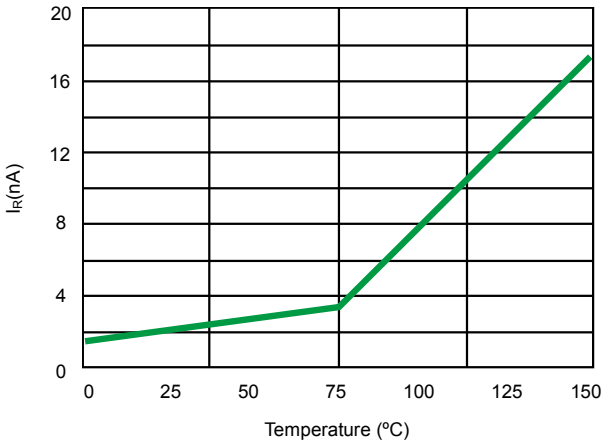


Fig 4.Typical Leakage Current vs. Temperature

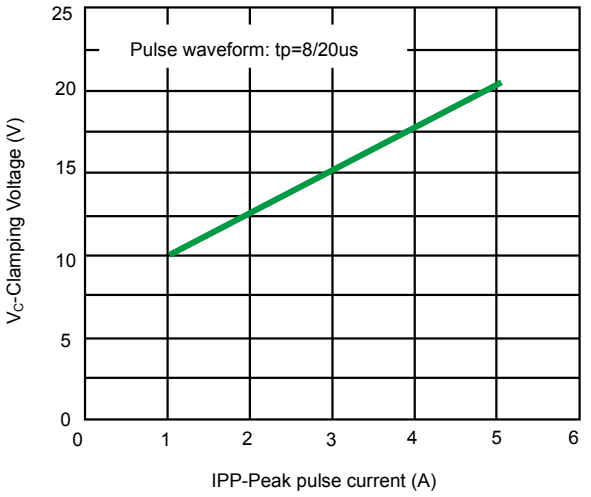


Fig 5. Clamping voltage vs. Peak pulse current

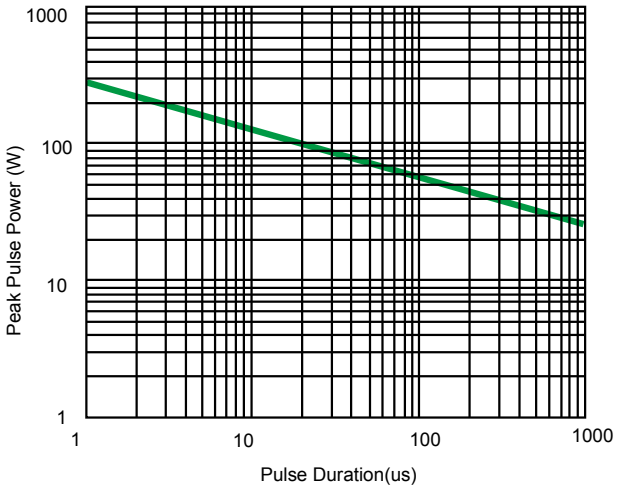
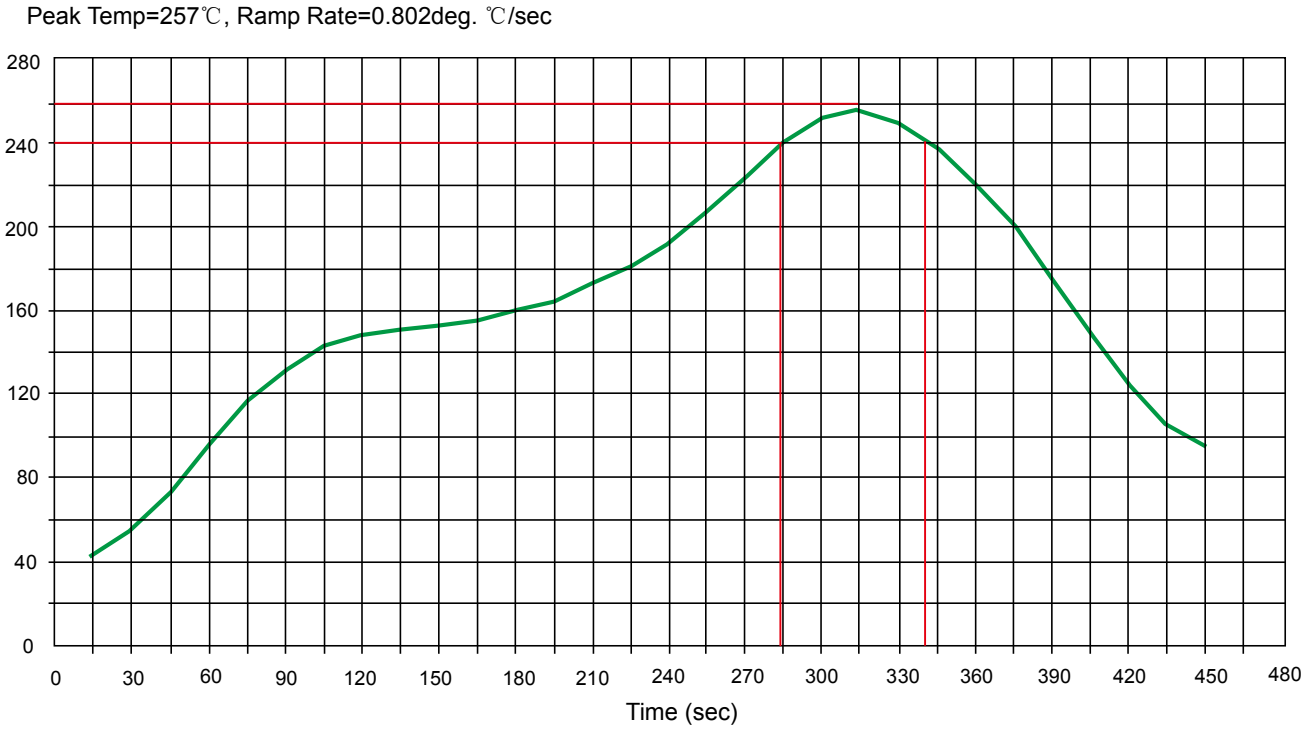


Fig 6. Non-Repetitive Peak Pulse Power vs. Pulse time

Solder Reflow Recommendation



Solder Reflow Recommendation

For TVS diodes a low-ohmic and low-inductive path to chassis earth is absolutely mandatory in order to achieve good ESD protection. Novices in the area of ESD protection should take following suggestions to heart:

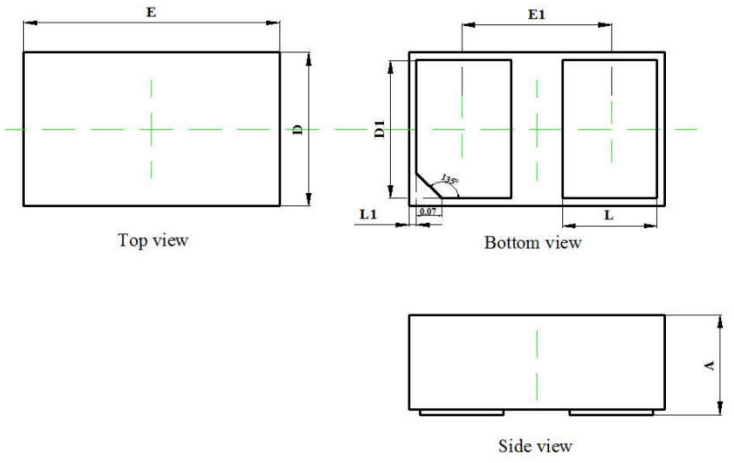
- Do not use stubs, but place the cathode of the TVS diode directly on the signal trace.
- Do not make false economies and save copper for the ground connection.
- Place via holes to ground as close as possible to the anode of the TVS diode.
- Use as many via holes as possible for the ground connection.
- Keep the length of via holes in mind! The longer the more inductance they will have.

Ordering information

Package	Packing Description	Packing Quantity
DFN1006-2L	Tape/Reel,7”reel	10000PCS/Reel 400000PCS/Carton

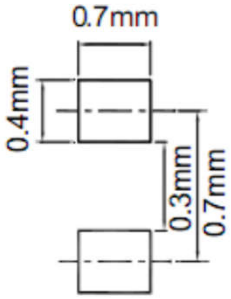
Package Dimensions

DFN1006-2L



Dim.	Millimeter(mm)		Inches	
	Min.	Max.	Min.	Max.
A	0.350	0.450	0.014	0.018
D	0.550	0.650	0.022	0.026
E	0.950	1.050	0.037	0.041
D1	0.420	0.520	0.017	0.020
E1	0.550	0.650	0.022	0.026
L	0.270	0.370	0.011	0.015
L1	-	0.100	-	0.004

The recommended mounting pad size



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